

Process/Voltage/Temperature Sensor (Supply voltage 1.8V/0.9V)

028UMC_PVT_01 IP library is a unique solution intended to continuously monitor IC status at several on-die locations.

It is able to detect manufacturing process deviation, perform voltage and die temperature measurement. PVT Sensor IP library consists of three main parts: VT module as a calculation center for wide range of voltage and temperature measurements; Voltage/Temperature sensor units for voltage measurements from 0.6V to 3.63V and temperature measurements from -40°C to +125°C; Process detector module includes process units, dedicated for process variation elicitation of transistors with different threshold voltage types.

PVT Sensor can operate in Glitch detector mode allowing to monitor and detect rapid fluctuations of voltage and temperature on the die.

IP technology: UMC 28nm HPC+. IP status: pre-silicon verified.

Area: 0.124mm² for Voltage/temperature processing module 0.0063mm² for Process detector unit; 0.0017mm² for sensor unit09

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ELECTRICAL CHARACTERISTICS								
Parameter	Symbol	Conditions		Min	Тур	Max	Units	
Core supply voltage	$ m V_{DD09}$	-		0.81	0.9	0.99	V	
IO supply voltage	V_{DD18}	-		1.62	1.8	1.98	V	
Operating temperature range	Ti	-		-40	27	+125	°C	
VT module current consumption	ī	@V _{DD09} @V _{DD18}		-	0.3	4.5	uA	
during measurements	I_{CC_VT}			-	188	245		
Process detector current	I	$@V_{DD09}$		-	70	130	uA	
consumption during measurements	I_{CC_PD}	$@V_{DD18}$		-	505	795		
Shutdown current	I_{SHD}	VT module	@V _{DD09}	-	2	2000		
		EN=0	$@V_{DD18}$	-	4	1800	nA	
		Process detector,	$@V_{DD09}$	-	2.7	1000		
		PD_EN=0	$@V_{DD18}$	-	3.9	1200		
Input-logic level high	$V_{ m IH}$	-		$0.9V_{\mathrm{DD09}}$	-	$1.1V_{DD09}$	V	
Input-logic level low	$V_{ m IL}$	-		0	-	$0.1V_{DD09}$	V	
Output-logic level high	V_{OH}	-		$0.9V_{DD09}$	-	$1.1V_{DD09}$	V	
Output-logic level low	V_{OL}	-		0	-	$0.1V_{DD09}$	V	
Output DATA resolution	K	-		-	10	-	bit	
Input clock frequency	f_{CLK_IN}	± 1%		50	-	12750	kHz	
Voltage measurement accuracy for	A_{V09}	W/o trimming, voltage measurement range 0.58V to 0.92V		-	-	2	%	
0.9V VT sensor unit	Αν09							
Voltage measurement accuracy for	$A_{\rm V18}$	W/o trimming, voltage measurement range 1.0V to 2.0V		-	-	2.2	%	
1.8V VT sensor unit	AVI8							
Voltage measurement accuracy for	A_{V33}	W/o trimming, for voltage measurement range 1.5V to 3.63V		-	-	2.6	%	
3.3V VT sensor unit	1 1 V 33							
Voltage measurement accuracy for	A_{V_VBAT}	W/o trimming, voltage measurement range 0.8V to 3.63V		-	-	3.5	%	
Vbat VT sensor unit	TIV_VBAI							
Main temperature measurement	T_{MR}	_		-40	_	+125	°C	
range	1 MK			10				
Temperature measurement accuracy	A_{T}	W/o trimming		-	-	±6.4	°C	
		With trimming method T1 (over 80 °C)		-	-	±3.2	°C	
		With trimming method T2.A		-	-	±2.3	°C	
		With trimming method T2.B		-	-	±3.4	°C	
		With trimming method T3		-	-	±1.6	°C	